Supertex inc.



Preliminary

Universal Relay Driver

Features

- 8V to 450V Input Voltage Range
- Energy Saving Hold Current Mode
- Adjustable Microcontroller Supply
- □ Low Supply Current <1mA</p>
- Constant Current Coil Drive
- Programmable Pull-in Current, Pull-in Time, and Hold Current
- Efficient PWM Operation Using the Relay Coils' Inductance

Applications

- Industrial Controls
- Relay Timers
- White Goods
- Solenoid Drivers
- Home Automation

General Description

The Supertex HV9901 is a BiCMOS/DMOS universal relay driver that employs PWM switching techniques. It is designed for efficient and energy-saving operation of a low voltage relay with supply voltages ranging from 8 to 450V DC through utilization of the relay coils' inductance.

The circuit is capable of operating over a wide input voltage range without requiring a change of any external components. For example, this will enable users to use 5V coil relays for DC voltages 8 - 450V or AC voltages up to 240V.

The HV9901 has an internal high-voltage regulator to power internal PWM circuitry. Additionally it includes an adjustable auxiliary regulator with a 1mA capability that can be used to supply low power microcontrollers.

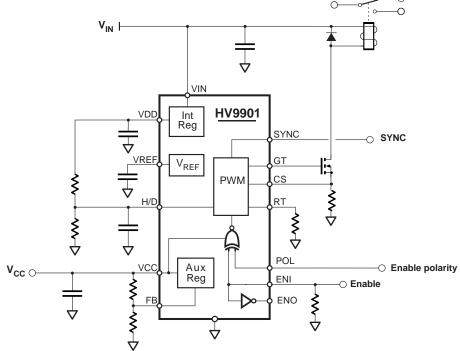
The pull-in current, pull-in time and hold current are all programmable using only two resistors and a capacitor. The PWM switching frequency can be either

- Synchronized to an external clock, or
- Synchronized to other HV9901s, where the synchronized frequency is the highest free-running frequency

The enable (ENI) logic input is used to turn the relay on/off. Enable polarity may be selected via the POL input. Audible noise is prevented using fixed switching frequencies above 20kHz.

WARNING!!! Galvanic isolation is not provided. Dangerous voltages are present when connected to the AC line. It is the responsibility of the designer to ensure adequate safeguards are in place to protect the end user from electrical shock.

Typical Application Circuit



06/25/02

Ordering Information

Package	Options
16 Lead Plastic DIP	16 Lead Plastic SO
HV9901P	HV9901NG

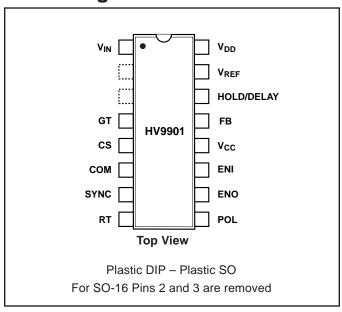
Absolute Maximum Ratings

Input voltage, V _{IN} ²	-0.5 to +470V
Input voltage to any other pin ²	-0.3V to V _{DD} +0.3V
Continuous total power dissipation for DIP	1000 mW ¹
Continuous total power dissipation for SO	750 mW ¹
Operating Temperature Range	-40 to +85°C

Note 1: For operation above 25°C ambient derate linearly at 7.5 mW/°C.

Note 2: All voltages are referenced to COM.

Pin Configuration



Electrical Characteristics

(T_A = 25°C, unless otherwise specified)

Symbol Parameters	Min	Тур	Max	Unit	Conditions
			•		

High Voltage Regulator

V _{IN}	Input Voltage	8.0		450	V	I _{CC} = 0.25mA load
VIN	input voltage	10		450	V	I _{CC} = 1.0mA load
I _{IN}	Supply Current			2.0	mA	no load at $V_{DD,}$ load at I_{CC} =1mA, C_{GT} = 500pF, f_{OSC} = 25 KHz
V_{DD}	Regulator Output Voltage	7.0	7.5	7.8	V	no load at $V_{DD,}$ load at I_{CC} =1mA, C_{GT} = 500pF, f_{OSC} = 25 KHz
V _{UVLO}	V _{DD} Under Voltage Lockout	6.4	6.7	7.0	V	

Adjustable Regulator

V _{CC}	Regulator Output Voltage Range	2.0		5.5	V	I _{CC} =1.0mA load
I _{CC}	Regulator Output Current	0		1.0	mA	no load at V _{DD} , See Note
V _{FB}	Feed Back Voltage	0	V _{REF}	V _{DD} -1.0V	V	
I _{FB}	Input Bias Current		25	100	nA	$V_{FB} = V_{REF}$

Note: Maximum allowable load current limited by power dissipation and operating ambient temperature.

Reference (T_A=25°C unless otherwise noted)

V_{REF}	Bandgap Reference Voltage	1.22	1.25	1.28	V	$T_A = 25^{\circ}C$
V_{REF}	Bandgap Reference Voltage	1.20	1.25	1.30	V	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$
V_{REF}	Load Regulation			7.0	mV	0mA < I _{REF} < 0.3mA
V_{REF}	Line Regulation		2.0	5.0	mV	6V < V _{DD} < 8V
I _{REF(SHORT)}	Short Circuit Current			1.0	mA	
I _{REF(SINK)}	Reference Voltage Sink Current			20	μΑ	

Electrical Characteristics

(T_A = 25°C, unless otherwise specified)

Symbol Parameters	Min	Тур	Max	Unit	Conditions
Oscillator					
	20	25	25	LU-	P = 1.00MO

4	DWM Cocillator Fraguency	20	25	35	kHz	$R_T = 1.00M\Omega$
tosc	PWM Oscillator Frequency	80	100	140	kHz	$R_T = 226K\Omega$
	Temperature Coefficient		170		ppm/°C	T_A = -40°C to +85°C
f _{SYNC}	Oscillator Sync Frequency			150	kHz	
SYNC	Sync. Input/Output Sourcing Current	20		55	μΑ	
SYNC	Sync. Input/Output Sinking Current	1.0			mA	V _{SYNC} = 0.1V
V _{SYNC}	Sync Input Logic Low Voltage			1.0	V	

PWM

D _{MAX}	Maximum Duty Cycle	96.5	99.5	%	$R_T = 1.00M\Omega$
D _{MAX}	Maximum Duty Cycle	86.5	97.5	%	$R_T = 225K\Omega$
P _{MIN}	Minimum Output Pulse Width	100	200	nsec	

MOSFET Driver Output

V _{GTH}	Gate Drive Output High	V _{DD} - 0.3			V	I _{OUT} = 10 mA
$V_{\rm GTL}$	Gate Drive Output Low			0.3	V	I _{OUT} = -10 mA
t _R	Rise Time		30	50	nsec	C _{GT} = 500pF
t _F	Fall Time		30	50	nsec	C _{GT} = 500pF

Current Sensing

V _{CS(HL)}	Current Sense Voltage, high limit	0.775	0.833	0.891	V	
t _{DELAY(HL)}	Current limit delay to GT high limit		200	250	ns	V _{CS} = 0.88 Volts
I _{CS}	Input Bias Current		25	1000	nA	POL=LOW, ENI=LOW
V _{OS}	Low limit comparator input offset voltage			±60	mV	
t _{DELAY(LL)}	Current limit delay to GT, low limit		200	250	ns	V _{CS} =0.47V, V _{HOLD} =0.417V
V _{HOLD/DEL}	Hold/Delay output voltage	V _{DD} -0.4			V	I _{HOLD/DEL} (Sourcing)-100μA, POL=LOW, ENI=HIGH
I _{HOLD/DEL}	Hold Delay Input Bias Current		25	500	nA	POL=LOW, ENI=LOW

Electrical Characteristics, continued

 $(T_A = 25^{\circ}C, \text{ unless otherwise specified})$

Symbol Parameters Min Typ Max Unit Conditions

Enable Logic

t _{ENI}	Shutdown Delay		50	100	nsec	2V < V _{CC} < 5.5V	
V _{ENI}	Enable Input Voltage - High	0.7V _{CC}		V _{CC}	V	2V < V _{CC} < 5.5V	
V _{ENI}	Enable Input Voltage - Low	0		0.3V _{CC}	V	2V < V _{CC} < 5.5V	
I _{ENI}	Enable Input Current - High		1.0	5.0	μΑ	μA 2V < V _{CC} < 5.5V	
I _{ENI}	Enable Input Current - Low	-5.0	-1.0		μA 2V < V _{CC} < 5.5V		
V _{POL}	Polarity Voltage - High	0.7V _{CC}		V _{CC}	V	2V < V _{CC} < 5.5V	
V _{POL}	Polarity Voltage - Low	0		0.3V _{CC}	V	2V < V _{CC} < 5.5V	
I _{POL}	Polarity Current - High		1.0	5.0	μΑ	2V < V _{CC} < 5.5V	
I _{POL}	Polarity Current - Low	-5.0	-1.0		μΑ	2V < V _{CC} < 5.5V	
V _{ENO}	Enable Output Voltage - High	0.9V _{CC}		V _{CC}	V	2V < V _{CC} < 5.5V	
V _{ENO}	Enable Output Voltage - Low	0		0.1V _{CC}	V	2V < V _{CC} < 5.5V	

Enable Logic Truth Table

POL	ENI	ENO	Gate Drive Output	
LOW	LOW	HIGH	V _{GT} = Oscillating Output, Duty Cycle depends on Inductive Load	
LOW	HIGH	LOW	V _{GT} = LOW, SYNC = HIGH, Oscillator shut down.	
HIGH	HIGH	LOW	V _{GT} = Oscillating Output, Duty Cycle depends on Inductive Load	
HIGH	LOW	HIGH	V _{GT} = LOW, SYNC = HIGH, Oscillator shut down.	

Applications Information

$$I_{PULL-IN} = \frac{V_{CS(HL)}}{R_{SENSE}}$$
 $V_{CS(HI)} = 833 \text{mV nom}$

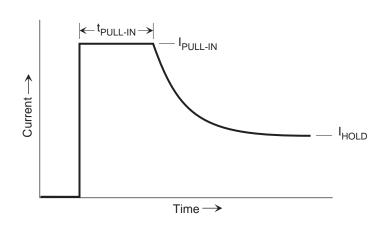
$$V_{CS(LL)} = \frac{V_{DD}}{1 + \frac{R_{HD9}}{R_{HD6}}}$$
 $V_{DD} = 7.5 \text{V nom}$

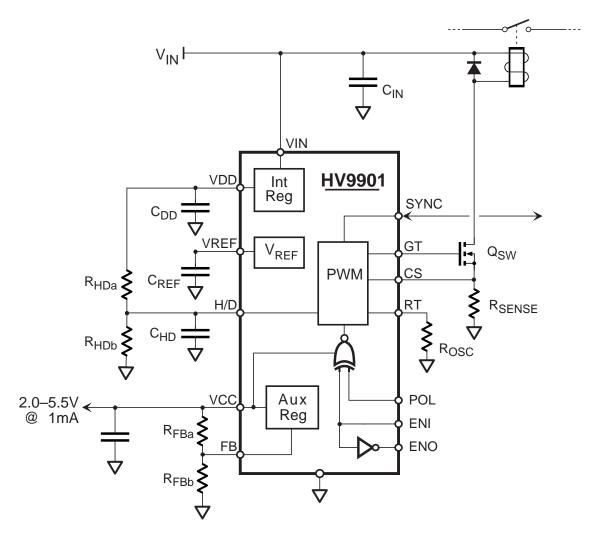
$$I_{HOLD} = \frac{V_{CS(LL)}}{R_{SENSE}}$$

$$t_{PULL-IN} = - \left(R_{HDa} \left\| R_{HDb} \right) C_{HD} \ln \left(1 - \frac{V_{CS(HL)} - V_{DD}}{V_{CS(LL)} - V_{DD}} \right) \right.$$

$$f_{PWM} \approx 3.23 \mathrm{kHz} + \frac{21.8 \mathrm{GHz} \cdot \Omega}{R_{OSC}} \quad \text{(valid for f}_{pwm} > 23 \mathrm{kHz}\text{)}$$

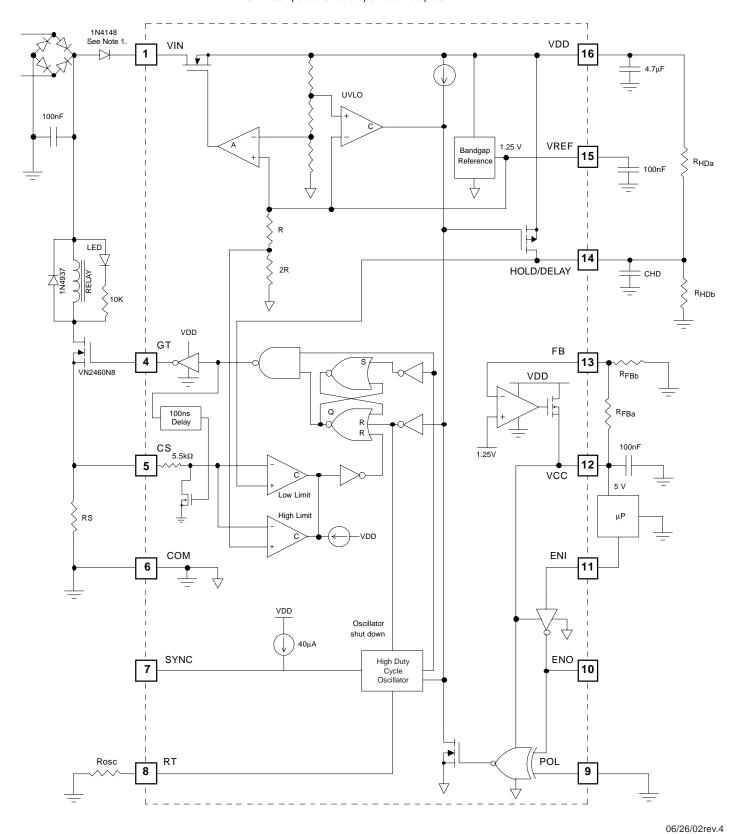
$$V_{CC} = 1.25 \text{V} \left(1 + \frac{R_{FBa}}{R_{FBb}} \right)$$





Functional Block Diagram and Typical Application

- Notes: 1. This diode and bridge rectifier required only for AC operation.
 - 2. For non-isolated AC operation the entire circuit must be floating.
 - 3. All comparators have open drain outputs.



Supertex inc.